NSN 5962-01-431-2561

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View Online at https://aerobasegroup.com/nsn/5962-01-431-2561 **Body Length:** 0.640 inches **Body Width:** 0.420 inches **Body Height:** 0.090 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacerspecial **Features Provided:** Bipolar and electrostatic sensitive and monolithic and programmed and radiation hardened **Inclosure Material:** Metal and ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Criticality Code Justification:** Cbbl **Case Outline Source And Designator:** F-6 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuit, read only memory Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:**

Rom

Special Features:

Altered item, altered by programming; program media id 5055507, file name horiza.4; make from p/n 5962-8552704kx

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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24 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0